



0.2A SBR SURFACE MOUNT SUPER BARRIER RECTIFIER

Product Summary

V _{RRM} (V)	I _O (A)	V _{F (MAX)} (V) @ +25°C	I _{R (MAX)} (mA) @ +25°C
40	0.2	0.59	0.01

Description and Applications

Packaged in X1-DFN1006-2 (SWP) (Type C) package, provides very low V_F and excellent reverse-leakage stability at high temperatures. It is ideal for use as a rectifier, freewheel diode or blocking diode in:

- DC-DC Converters
- AC-DC Adaptors



Top View

Features and Benefits

- Patented Trench Super Barrier Rectifier SBR[®] Technology
- With Visible And Solderable Side Pads
- Ultra-Low Forward Voltage Drop
- Superior Reverse Avalanche Capability
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: X1-DFN1006-2 (SWP) (Type C)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish. Solderable per MIL-STD-202, Method 208 ³
- Weight: 0.0854mg (Approximate)



Bottom View

Ordering Information (Note 4)

Part Number	Case	Packaging
SBR0240LPW-7B	X1-DFN1006-2 (SWP) (Type C)	10,000/Tape & Reel

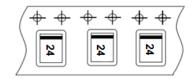
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



24 = Product Type Marking Code Bar Denotes Cathode





Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	40	>
Average Rectified Output Current (See Figure 1)	lo	200	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	5	Α

Thermal Characteristics

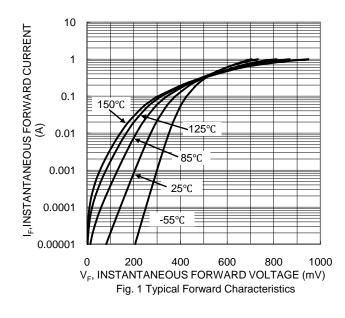
Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Ambient T _A = +25°C (Note 5)	$R_{ heta JA}$	320	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

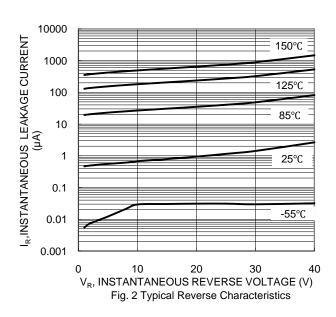
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop		_	0.15	0.21		I _F = 0.1mA, T _J = +25°C
		_	0.22	0.28		$I_F = 1.0 \text{mA}, T_J = +25 ^{\circ}\text{C}$
	VF	_	0.29	0.35	V	$I_F = 10 \text{mA}, T_J = +25 ^{\circ}\text{C}$
	VF	_	0.38	0.49	V V	$I_F = 100 \text{mA}, T_J = +25 ^{\circ}\text{C}$
		_	0.45	0.59		$I_F = 200 \text{mA}, T_J = +25 ^{\circ}\text{C}$
		_	0.42	0.56		I _F = 200mA, T _J = +125°C
			1.5	_		V _R = 25V, T _J = +25°C
Leakage Current (Note 6)	I _R	_	2.5	10	μA	$V_R = 40V, T_J = +25^{\circ}C$
			500	_		$V_R = 40V, T_J = +125$ °C
Total Capacitance	C _T	_	8	_	pF	$V_R = 5V$, $f = 1MHz$
Reverse Recovery Time	t _{RR}	_	3.8	_	ns	I _F = 10mA, I _{RRM} = 0.1I _R , T _A = +25°C

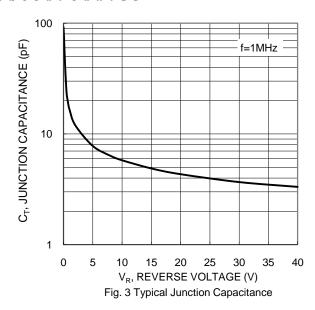
Notes:

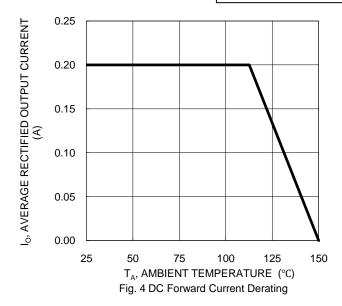
- 5. 1*MRP FR-4 PC board 2oz. copper, minimum recommended pad layout per http://www.diodes.com/package-outlines.html.
- 6. Short duration pulse test used to minimize self-heating effect.

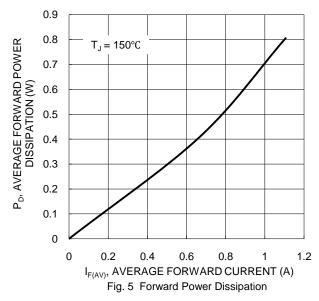










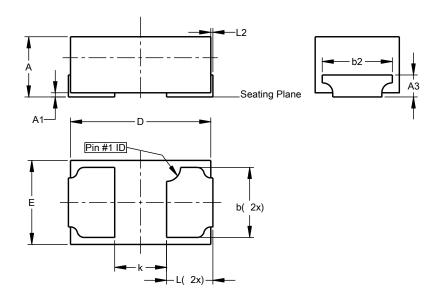




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1006-2 (SWP) (Type C)

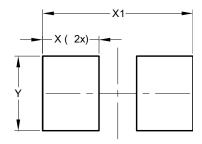


X1-DFN1006-2 (SWP)					
(Type C)					
Dim	Min	Max	Тур		
Α	0.37	0.47	0.42		
A1	0.00	0.05	0.03		
A3	0.17 REF				
b	0.47	0.57	0.52		
b2	0.55 REF				
D	0.95	1.05	1.00		
Ε	0.55	0.65	0.60		
k	0.37 REF				
L	0.28	0.38	0.33		
L2	0.15 REF				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1006-2 (SWP) (Type C)



Dimensions	Value	
Dimensions	(in mm)	
Х	0.45	
X1	1.20	
Y	0.60	



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